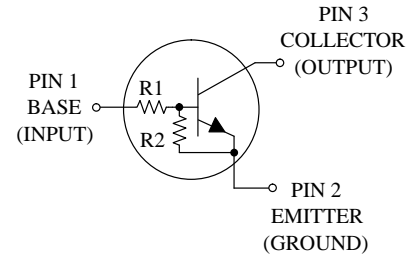


**2214,                    2214 ,**  
**5214,                    114 ,**  
**114    3,                    114    3**

**g**   **➤**                    **➤**   **(   )**  
**1   10k Ω,   2   4 k Ω**

## NPN Transistors with Monolithic Bias Resistor Network

This series of digital transistors is designed to replace a single



MARKINIS 1 0 0 1 3.742 -.794 cm 0 4rr.-.7165 lc.

Collector-Emitter Voltage	$V_{CEO}$	50	Vdc
Collector Current – Continuous	$I_C$	100	mAdc
Input Forward Voltage	$V_{IN(fwd)}$	40	Vdc
Input Reverse Voltage	$V_{IN(rev)}$	6	Vdc

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



See detailed ordering, marking, and shipping information in

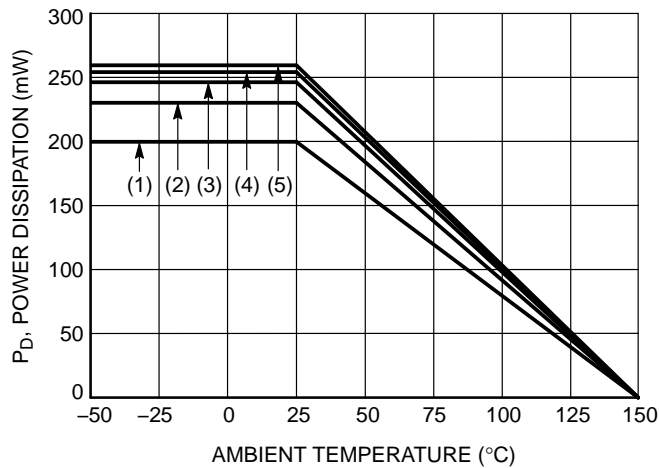
# MUN2214, MMUN2214L, MUN5214, DTC114YE, DTC114YM3, NSBC114YF3

**Table 1. ORDERING INFORMATION**

Device	Part Marking	Package	Shipping†
MUN2214T1G, SMUN2214T1G*	8D	SC-59 (Pb-Free)	3000 / Tape & Reel
MUN2214T3G, SMUN2214T3G*	8D	SC-59 (Pb-Free)	10000 / Tape & Reel
MMUN2214LT1G, SMMUN2214LT1G*	A8D	SOT-23 (Pb-Free)	3000 / Tape & Reel
MUN5214T1G, SMUN5214T1G*	8D	SC-70/SOT-323 (Pb-Free)	3000 / Tape & Reel
DTC114YET1G, SDTC114YET1G	8D	SC-75 (Pb-Free)	3000 / Tape & Reel
DTC114YM3T5G, NSVDTC114YM3T5G*	8D	SOT-723 (Pb-Free)	8000 / Tape & Reel
NSBC114YF3T5G	J	SOT-1123 (Pb-Free)	8000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*S and NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable.



- (1) SC-75 and SC-70/SOT-323; Minimum Pad
- (2) SC-59; Minimum Pad
- (3) SOT-23; Minimum Pad
- (4) SOT-1123; 100 mm<sup>2</sup>, 1 oz. copper trace
- (5) SOT-723; Minimum Pad

**Figure 1. Derating Curve**



Table 2. THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
<b>THERMAL CHARACTERISTICS (SOT-1123) (NSBC114YF3)</b>			
Total Device Dissipation $T_A = 25^\circ\text{C}$  Derate above $25^\circ\text{C}$	(Note 3) (Note 4) (Note 3) (Note 4)	$P_D$  254 297 2.0 2.4	mW  mW/ $^\circ\text{C}$
Thermal Resistance, Junction to Ambient	(Note 3) (Note 4)	$R_{\theta JA}$  493 421	$^\circ\text{C/W}$
Thermal Resistance, Junction to Lead	(Note 3)	$R_{\theta JL}$  193	$^\circ\text{C/W}$
Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

1. FR-4 @ Minimum Pad.
2. FR-4 @ 1.0 x 1.0 Inch Pad.
3. FR-4 @ 100 mm<sup>2</sup>, 1 oz. copper traces, still air.
4. FR-4 @ 500 mm<sup>2</sup>, 1 oz. copper traces, still air.

Table 3. ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ , unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
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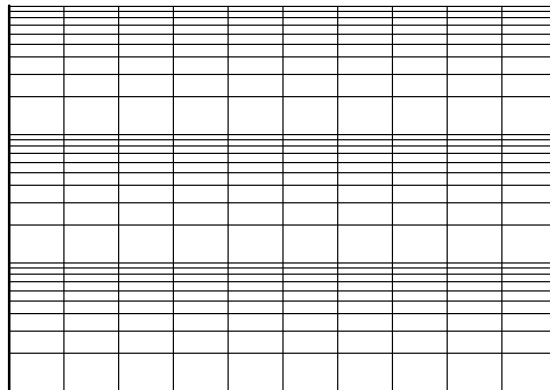
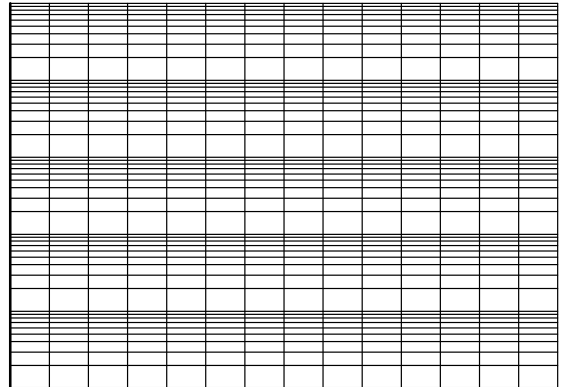
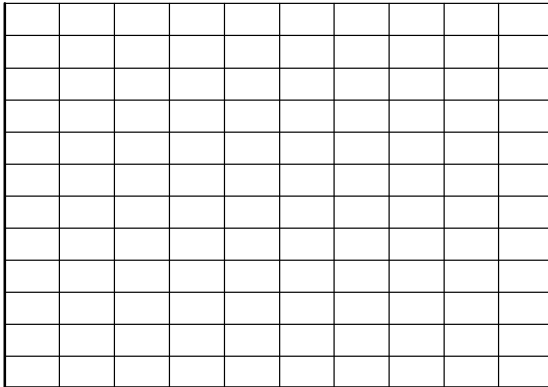
**OFF CHARACTERISTICS**

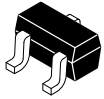
Collector-Base Cutoff Current

( $V_{CB} = 50\text{ V}, I_E = 0$ ) = 0.055 36.737 .9071 re 0 6 6 (OFF 500.655 35.119  $T_c(CB)T_j$  8 0370 8 5 6 (20.6244 6800 m3-.0021 Of348.945 515.2500.655 .907



TYPICAL CHARACTERISTICS  
NSBC114YF3



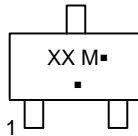


SCALE 4:1

**SC-70 (SOT-323)**  
CASE 419  
ISSUE R

DATE 11 OCT 2022

**GENERIC  
MARKING DIAGRAM**



- XX = Specific Device Code
- M = Date Code
- = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking.  
Pb-

STYLE 1:  
CANCELLED

STYLE 2:  
PIN 1. ANODE  
2. N.C.  
3. CATHODE

STYLE 3:  
PIN 1. BASE  
2. EMITTER  
3. COLLECTOR

STYLE 4:  
PIN 1. CATHODE  
2. CATHODE  
3. ANODE

STYLE 5:  
PIN 1. ANODE  
2. ANODE  
3. CATHODE

STYLE 6:  
PIN 1. EMITTER  
2. BASE  
3. COLLECTOR

STYLE 7:  
PIN 1. BASE  
2. EMITTER  
3. COLLECTOR

STYLE 8:  
PIN 1. GATE  
2. SOURCE  
3. DRAIN

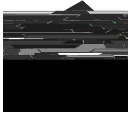
STYLE 9:  
PIN 1. ANODE  
2. CATHODE  
3. CATHODE-ANODE

STYLE 10:  
PIN 1. CATHODE  
2. ANODE  
3. ANODE-CATHODE

STYLE 11:  
PIN 1. CATHODE  
2. CATHODE  
3. CATHODE





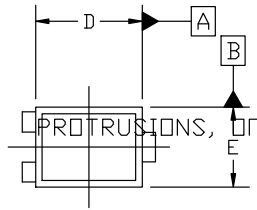


**SOT-1123 0.80x0.60x0.37, 0.35P**  
**CASE 524AA**  
**ISSUE D**

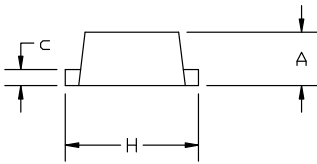
DATE 18 JAN 2024

NOTES:

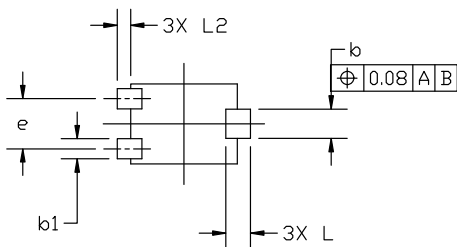
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. MAXIMUM LEAD THICKNESS, ASH,



TOP VIEW



SIDE VIEW

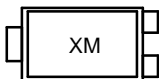


BOTTOM VIEW

← GATE BURRS.

MILLIMETERS			
DIM	MIN	NOM	MAX
A	0.34	0.37	0.40
b	0.15	0.22	0.2
			5
e	0.35	0.38	0.40
H	0.950	1.000	1.050
L	0.185 REF		
L2	0.05	0.10	0.15

**GENERIC MARKING DIAGRAM\***



- X = Specific Device Code
- M = Date Code

RECOMMENDED MOUNTING FOOTPRINT

\*

\*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1:  
 PIN 1. BASE  
 2. EMITTER  
 3. COLLECTOR

STYLE 2:  
 PIN 1. ANODE  
 2. N/C  
 3. CATHODE

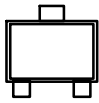
STYLE 3:  
 PIN 1. ANODE  
 2. ANODE  
 3. CATHODE

STYLE 4:  
 PIN 1. CATHODE  
 2. CATHODE  
 3. ANODE

STYLE 5:  
 PIN 1. GATE  
 2. SOURCE  
 3. DRAIN

SOT-723 1.20x0.80x0.50, 0.40P

GENERIC  
MARKING



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